## VS-30CTQ050-M3, VS-30CTQ060-M3



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# High Performance Schottky Rectifier, 2 x 15 A



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub> 2 x 15 A						
V <sub>R</sub>	50 V, 60 V					
V <sub>F</sub> at I <sub>F</sub>	0.56 V					
I <sub>RM</sub> typ.	45 mA at 125 °C					
T <sub>J</sub> max.	150 °C					
E <sub>AS</sub>	13 mJ					
Package	3L TO-220AB					
Circuit configuration	Common cathode					

### **FEATURES**

- 150 °C T<sub>J</sub> operation
- · Very low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### DESCRIPTION

This center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL CHARACTERISTICS VALUES UN							
I <sub>F(AV)</sub>	Rectangular waveform	30	А				
V <sub>RRM</sub>		50/60	V				
IFSM	t <sub>p</sub> = 5 μs sine	1000	А				
V <sub>F</sub>	15 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.56	V				
TJ	Range	-55 to +150	°C				

VOLTAGE RATINGS								
PARAMETER SYMBOL VS-30CTQ050-M3 VS-30CTQ060-M3 UNITS								
Maximum DC reverse voltage	V <sub>R</sub>	50	60	N/				
Maximum working peak reverse voltage	V <sub>RWM</sub>	50	00	V				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS				
Maximum average forward per device		50 % duty cycle at $T_C$ = 105 °C, rectangular waveform		30				
current, see fig. 5 per leg	I <sub>F(AV)</sub>			15				
Maximum peak one cycle non-repetitive	I <sub>FSM</sub>	5 $\mu$ s sine or 3 $\mu$ s rect. pulse	Following any rated load	1000	A			
surge current per leg, see fig. 7		10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	260				
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.50 A, L = 11.5 mH		13	mJ			
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1.50	А			

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS			
		15 A	T. = 25 °C	0.62	v			
Maximum forward voltage drop per leg See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	30 A	1j=25 C	0.82				
	VFM (")	15 A	T <sub>.1</sub> = 125 °C	0.56				
		30 A	1j = 125 C	0.71				
	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.80	mA			
Maximum reverse leakage current per leg		T <sub>J</sub> = 125 °C	V <sub>R</sub> = naleu V <sub>R</sub>	160				
Typical reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	45	mA			
Threshold voltage	V <sub>F(TO)</sub>			0.39	V			
Forward slope resistance	r <sub>t</sub>	$T_J = T_J maximum$		8.47	mΩ			
Maximum junction capacitance per leg	CT	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal ran	720	pF				
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 m	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs			

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storag temperature range	e	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C			
Maximum thermal resistance, junction to case per leg		P						
Maximum thermal resistance, junction to case per package		R <sub>thJC</sub>	DC operation	1.63	°C/W			
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50				
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum			6 (5)	kgf ⋅ cm			
	maximum			12 (10)	(lbf ⋅ in)			
Marking dovice			Case style 3L TO-220AB	30CTQ050				
Warking device	Marking device		Case signe SE TO-220AD	30CT	Q060			

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## VS-30CTQ050-M3, VS-30CTQ060-M3

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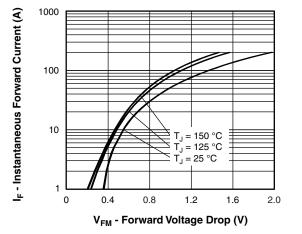


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

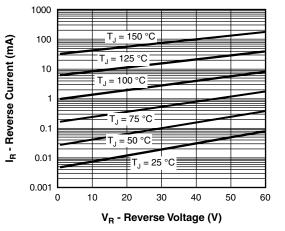


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

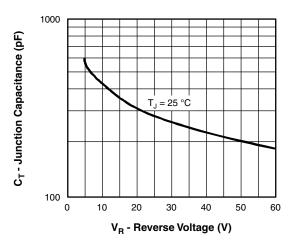


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

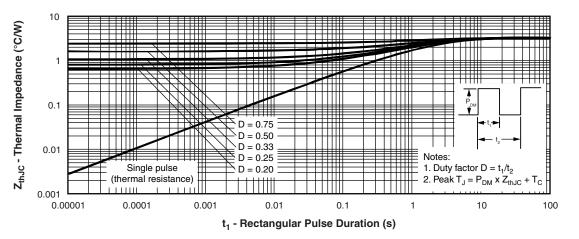
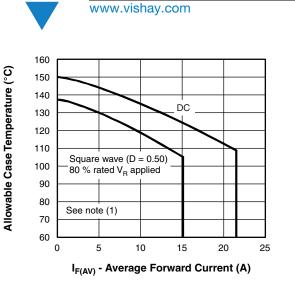


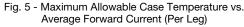
Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

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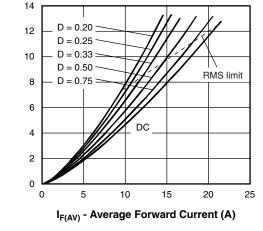
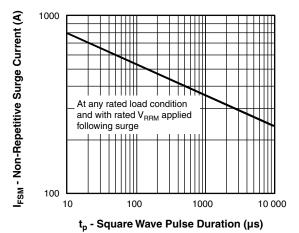


Fig. 6 - Forward Power Loss Characteristics (Per Leg)



Average Power Loss (W)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

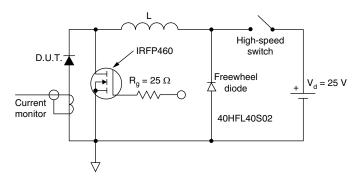


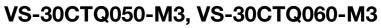
Fig. 8 - Unclamped Inductive Test Circuit

#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (1 \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = 10 \ \mathsf{V} \end{array}$

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### **ORDERING INFORMATION TABLE**

Device code	VS-	30	С	т	Q	060	-M3
	1	2	3	4	5	6	7
	1 · 2 · 3 · 4 ·	Cur Circ C = Pac T = Sch	rent ratii cuit confi commo kage: TO-220 ottky "Q	" series	30 A) n: de	oduct	050 = 5
	6 - 7 -	- Env		ngs — ntal digit gen-free,		complia	060 = 6

ORDERING INFORMATION (Example)							
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION							
VS-30CTQ050-M3	50	Antistatic plastic tubes					
VS-30CTQ060-M3 50 Antistatic plastic tubes							

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?96154</u>					
Part marking information	www.vishay.com/doc?95028				



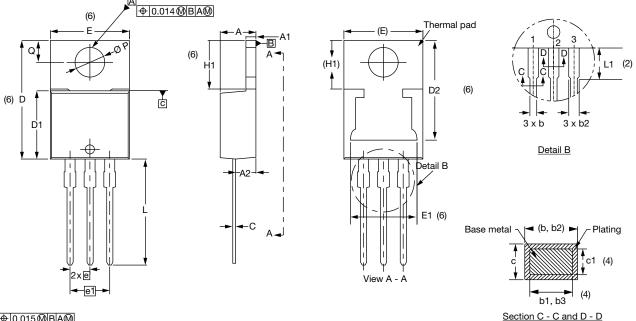
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### **TO-220AB 3L**

#### **DIMENSIONS** in millimeters and inches

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⊕0.015@BA@



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

SYMBOL	MILLIN	IETERS	INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Conforms to JEDEC<sup>®</sup> outline TO-220AB

#### Notes

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- <sup>(5)</sup> Controlling dimensions: inches
- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2, and E1
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2

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